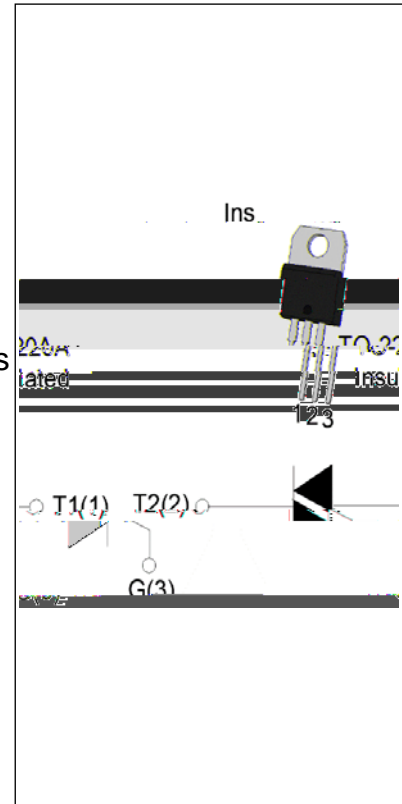


**JST06A-800BW 6A TRIAC**

Rev.A.1.1

**DESCRIPTION:**

The JST06A-800BW triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications such as heating regulation, induction motor starting circuits, for phase control operation in light dimmers, motor speed controllers. JST06A-800BW snubberless triac is especially recommended for use on inductive loads. By using an internal ceramic pad, JST06A-800BW provides a rated insulation voltage of 2500 VRMS, complying with UL standards (File ref: E252906). Package TO-220A is RoHS compliant.


**MAIN FEATURES**

Symbol	Value	Unit
$I_{T(RMS)}$	6	A
$V_{DRM}/V_{RRM}$	800	V
$I_{GT} / /$	50/50/50	mA

**ABSOLUTE MAXIMUM RATINGS**

Parameter	Symbol	Value	Unit
Storage junction temperature range	$T_{stg}$	-40-150	
Operating junction temperature range	$T_j$	-40-125	
Repetitive peak off-state voltage ( $T_j=25^\circ C$ )	$V_{DRM}$		
Repetitive peak reverse voltage ( $T_j=25^\circ C$ )	$V_{RRM}$		
RMS on-state current ( $T_c = 100^\circ C$ )	$I_{T(RMS)}$		
Non repetitive surge peak on-state current (full cycle, $t_p=20ms$ , $T_j=25^\circ C$ )	$I_{TSM}$	65	
Non repetitive surge peak on-state current (full cycle, $t_p=16.6ms$ , $T_j=25^\circ C$ )		72	
$I^2t$ value for fusing ( $t_p=10ms$ , $T_j=25^\circ C$ )	$^2t$	21	$^2s$
Critical rate of rise of on-state current ( $I_G=2 \times I_{GT}$ , $f=100Hz$ , $T_j=125^\circ C$ )	$di/dt$	100	A/ $\mu s$
Peak gate current ( $t_p=20\mu s$ , $T_j=125^\circ C$ )	$I_{GM}$	4	A
Average gate power dissipation ( $T_j=125^\circ C$ )	$P_{G(AV)}$	0.5	W

Peak gate power	$P_{GM}$	10	W
Peak pulse voltage ( $T_j=25$ ; non-repetitive,off-state;FIG.7)	$V_{pp}$	4	kV

**ELECTRICAL CHARACTERISTICS** ( $T_j=25$  unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
$I_{GT}$	$V_D=12V R_L=33$	- -	MAX.	50	mA
$V_{GT}$		- -	MAX.	1	V
$V_{GD}$		- -			

V V

=3

1

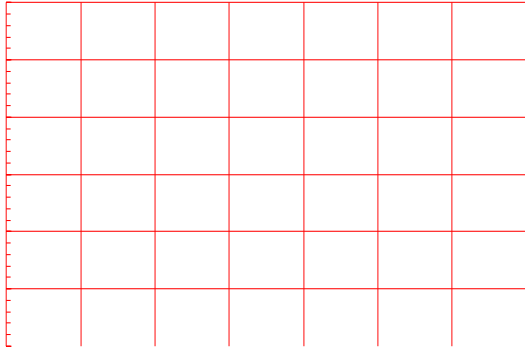
ORDERING INFORMATION

<b>J</b>	<b>ST</b>	<b>06</b>	<b>A</b>	<b>-800</b>	<b>BW</b>
JieJie Microelectronics Co., Ltd.	Triacs	$I_{T(RMS)}:6A$	A:TO-220A(Ins)	800:V <sub>DRM</sub> /V <sub>RRM</sub> 800V	BW:IGT1-3 50mA

MARKING

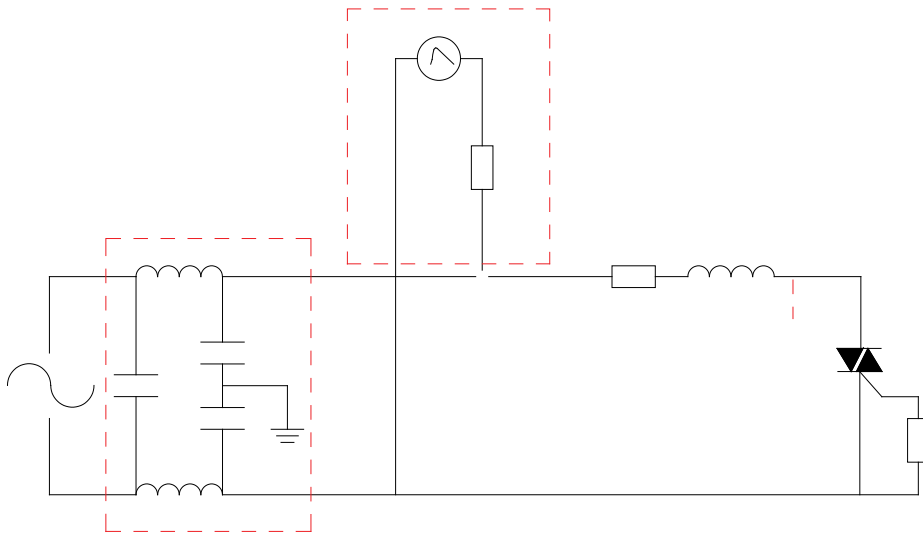


**FIG.1:** Maximum power dissipation versus RMS on-state current



**FIG.2:** RMS on-state current versus case temperature

FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



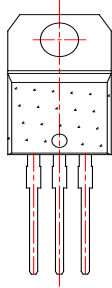
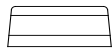
**ORDERING INFORMATION**

Order code	Voltage $V_{DRM}/V_{RRM}$ (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
		- -			
<b>JST06A-800BW</b>	<b>800</b>	<b>50</b>	<b>TO-220A(Ins)</b>	<b>50</b>	<b>Tube</b>

**Document Revision History**

Date	Revision	Changes
Apr.11, 2023	A.1.0	Last updated
Oct.11, 2025	A.1.1	Revise PACKAGE MECHANICAL DATA

**PACKAGE MECHANICAL DATA**



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